NSN 5961-01-175-1862

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Internal Configuration:
Junction contact
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
45.0 breakdown voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
1.00 milliamperes source cutoff current
Power Rating Per Characteristic:
750.0 milliwatts small-signal input power, common-collector megawatts
Transfer Ratio:
150.0 static forward current transfer ratio, common-emitter and 600.0 static forward current transfer ratio, common-emitter
Special Features:
Junction pattern arrangement: npn
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0